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Kind regards,

Team Nexperia

## PMEG1020EA

# 2 A ultra low V<sub>F</sub> MEGA Schottky barrier rectifier Rev. 04 — 30 December 2008 Pro

**Product data sheet** 

### **Product profile**

### 1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in SOD323 (SC-76) very small Surface-Mounted Device (SMD) plastic package.

#### 1.2 Features

- Forward current: I<sub>F</sub> ≤ 2 A
- Reverse voltage: V<sub>R</sub> ≤ 10 V
- Ultra low forward voltage
- Very small SMD plastic package

### 1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>F</sub>	forward current	$T_{sp} \le 55  ^{\circ}C$	-	-	2	Α
$V_R$	reverse voltage		-	-	10	V
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 1 A	[1] _	280	350	mV

[1] Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 



#### **Pinning information** 2.

Table 2. **Pinning** 

Description	Simplified outline	Graphic symbol
cathode	[1]	
anode	1 2	1
		sym001
	<b>Description</b> cathode	Description Simplified outline cathode

<sup>[1]</sup> The marking bar indicates the cathode.

#### **Ordering information** 3.

Table 3. **Ordering information** 

Type number	Package		
	Name	Description	Version
PMEG1020EA	SC-76	plastic surface-mounted package; 2 leads	SOD323

### **Marking**

Table 4. **Marking codes** 

Type number	Marking code
PMEG1020EA	E2

### **Limiting values**

Table 5. **Limiting values** 

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_R$	reverse voltage		-	10	V
I <sub>F</sub>	forward current	T <sub>sp</sub> ≤ 55 °C	-	2	Α
I <sub>FRM</sub>	repetitive peak forward current	$t_p \leq 1 \text{ ms; } \delta \leq 0.5$	-	3.2	Α
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; t <sub>p</sub> = 8 ms	-	9	Α
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

#### Thermal characteristics 6.

Table 6. Thermal characteristics

Cymahal	Devemeter	Conditions	Min	T	Mass	11!4
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> _	-	450	K/W
			[2]	-	210	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[3] _	-	90	K/W

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

### **Characteristics**

Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

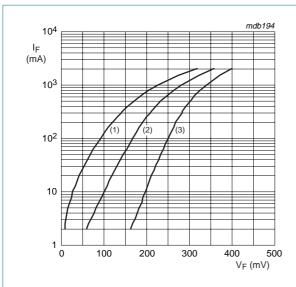
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{F}$	forward voltage		<u>[1]</u>			
		$I_F = 0.01 A$	-	100	130	mV
		$I_F = 0.1 A$	-	170	200	mV
		I <sub>F</sub> = 1 A	-	280	350	mV
		$I_F = 2 A$	-	350	460	mV
$I_R$	reverse current		[2]			
		$V_R = 5 V$	-	0.7	2	mA
		$V_R = 8 V$	-	1	2.5	mA
		$V_R = 10 V$	-	1.2	3	mA
$C_d$	diode capacitance	$V_R = 5 V$ ; $f = 1 MHz$	-	37	45	pF

<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ .

<sup>[2]</sup> Device mounted on an FR4 PCB with copper clad  $10 \times 10$  mm.

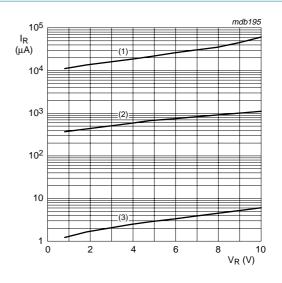
<sup>[3]</sup> Soldering point of cathode tab.

<sup>[2]</sup> For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.



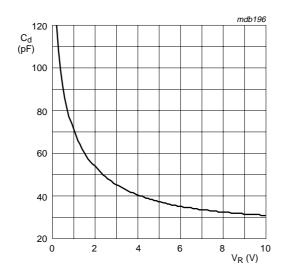
- (1)  $T_{amb} = 85 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = -40 \, ^{\circ}C$

Forward current as a function of forward Fig 1. voltage; typical values



- (1)  $T_{amb} = 85 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = -40 \, ^{\circ}C$

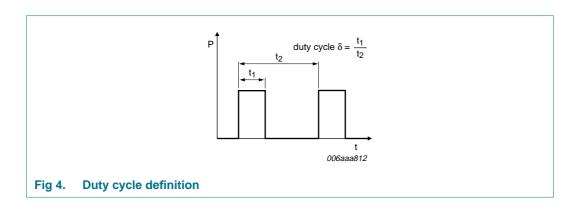
Fig 2. Reverse current as a function of reverse voltage; typical values



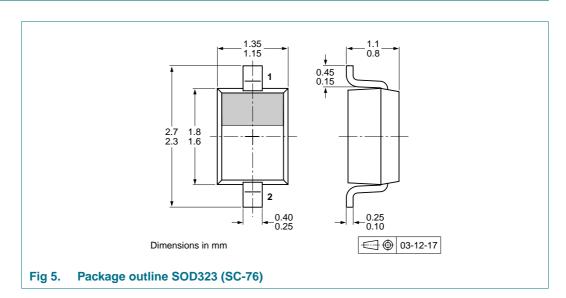
 $f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$ 

Fig 3. Diode capacitance as a function of reverse voltage; typical values

### 8. Test information



### 9. Package outline



### 10. Packing information

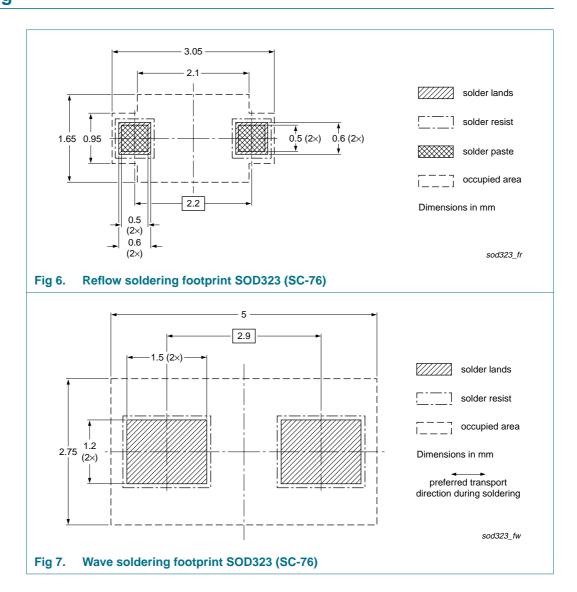
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			3000	10000
PMEG1020EA	SOD323	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see  $\underline{\text{Section 14}}$ .

### 11. Soldering



### 12. Revision history

### Table 9. Revision history

	-			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG1020EA_4	20081230	Product data sheet	-	PMEG1020EA_3
Modifications:		of this data sheet has been red of NXP Semiconductors.	designed to comply v	vith the new identity
	<ul> <li>Legal texts</li> </ul>	have been adapted to the new	company name whe	ere appropriate.
	<ul> <li>Section 13 <sup>c</sup></li> </ul>	"Legal information": updated		
PMEG1020EA_3	20040206	Product specification	-	PMEG1020EA_2
PMEG1020EA_2	20030715	Product specification	-	PMEG1020EA_1
PMEG1020EA_1	20030307	Preliminary specification	-	-

### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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### PMEG1020EA

### 2 A ultra low V<sub>F</sub> MEGA Schottky barrier rectifier

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